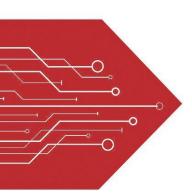
MSKSEMI















ESD

TVS

TSS

MOV

GDT

PLED

Broduct data speet



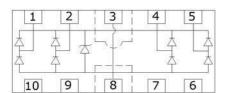


Features

- ◆ 150 Watts peak pulse power (tp = 8/20µs)
- ◆ Transient protection for high speed data lines to IEC 61000-4-2 (ESD) ±15kV (air), ±8kV (contact) IEC 61000-4-4 (EFT) 40A (5/50ns)
- ♦ Working voltages : 3.3V
- ♦ Protects two or four I/O lines
- ◆ Ultra Low capacitance:0.3pf (typical between I/O channel)
- Low operating and clamping voltages
- Solid-state silicon avalanche technology

Applications

- ♦ High Definition Multi-Media Interface (HDMI)
- ◆ USB 1.1/2.0/3.0/OTG
- ♦ IEEE 1394 Firewire Ports
- Projection TV Monitors and Flat Panel Displays
- Notebook Computers
- Set Top Box





DFN2510

Maximum Rating @ Ta=25°C unless otherwise specified

Symbol	Parameter	Ratings	Units
P _{PK}	Peak Pulse Power (tp = 8/20μs)	150	Watts
TL	Lead Soldering Temperature	260(10sec.)	$^{\circ}$
TJ	Operating Temperature	-55 to +125	$^{\circ}$
T _{STG}	Storage Temperature	-55 to +150	$^{\circ}$

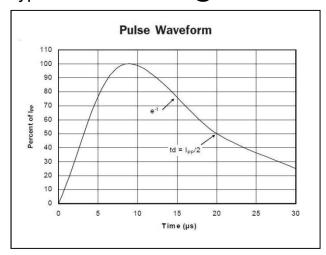
Electrical Characteristics@ Ta=25°C unless otherwise

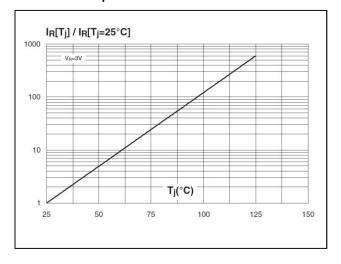
Symbol	Parameter	Conditions	Min.	Тур.	Max.	Units
V_{RWM}	Reverse Working Voltage	Any I/O to Ground		3.3		V
V_{BR}	Reverse Breakdown Voltage	I_T = 1mA, Any I/O to Ground	4.5			V
I _R	Reverse Leakage Current	V _{RWM} = 5V, Any I/O to Ground			1	μΑ
V _F	Diode Forward Voltage	I _F = 15mA		0.85	1.2	V
Vc		I_{PP} = 1A, tp =8/20µs, any I/O pin to Ground			9.8	٧
	Clamping Voltage	I_{PP} = 5A, tp =8/20µs, any I/O pin to Ground			15	V
Сл	l b	V _R = 0V, f = 1MHz, between I/O pins		0.25	0.3	pF
	Junction Capacitance	V_R = 0V, f = 1MHz, any I/O pin to Ground		0.5	0.6	pF

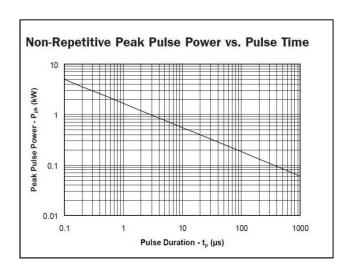


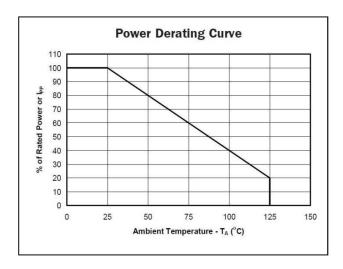


Typical Characteristics@ Ta=25°C unless otherwise specified



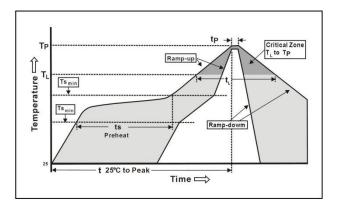






Soldering Parameters

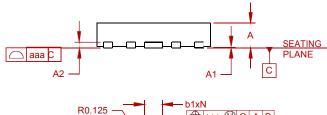
Reflow Co	ndition	Fb – Free assembly	
	-Temperature Min (T _{s(Min)})	150°C	
Pre Heat	- Temperature Max (T _{s(Max)})	200°C	
	-Time (Min to max) (t _s)	60 – 180 secs	
Average rate (T _L) to pea	amp up rate (Liquidus) Temp k	3°C/second Max	
T _{s (Max)} to T _L - Ramp-up Rate		3°C/second Max	
Reflow	-Temperature (T _L) (Liquidus)	217°C	
Reliow	-Temperature (t _L)	60 – 150 seconds	
Peak Temperature (Tp)		250*0/-5 °C	
Time with Temperate	in 5°C of actual peak ure (t _p)	20 – 40 seconds	
Ramp-dov	vm Rate	6°C/second Max	
Time 25°C	to peak Temperature (T _p)	8 minutes Max.	
Do not exc	ceed	260°C	

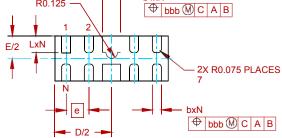


Semiconductor

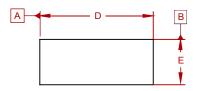
Compiance

PACKAGE MECHANICAL DATA



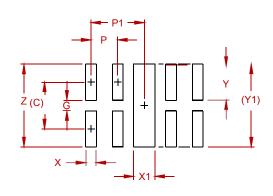


Dimensions in millimeters



DIMENSI ONS						
DIM	INC	HES		MILLIMETERS		
	MIN	NOM	MAX	MIN	NOM	MAX
Α	.020	.023	.026	0.50	0.58	0.65
A1	0.00	.001	.002	0.00	0.03	0.05
A2	0.)	005)		(0	(0.13)	
b	.006	.008	.010	0.15	0.20	0.25
b1	.014	.016	.018	0.35	0.40	0.45
D	.094	.098	.102	2.40	2.50	2.60
E	.035	.039	.043	0.90	1.00	1.10
е	.020 BSC			0.50	0.50 BSC	
L	.012	.015	.017	0.30	0.38	0.425
N	8			8		
aaa		.003		0.08		
bbb		.004		0.10		

Suggested Pad Layout



DIMENSIONS			
DIM	INCHES	MILLIMETERS	
С	(.034)	(0.875)	
G	.008	0.20	
Р	.020	0.50	
P1	.039	1.00	
Х	.008	0.20	
X1	.016	0.40	
Υ	.027	0.675	
Y1	(.061)	(1.55)	
Z	.061	1.55	

NOTES:

CONTROLLING DIMENSIONS ARE IN MILLIMETERS (ANGLES IN DEGREES). THIS LAND PATTERN IS FOR REFERENCE PURPOSES ONLY. CONSULT YOUR MANUFACTURING GROUP TO ENSURE YOUR COMPANY'S MANUFACTURING GUIDELINES ARE MET.

REEL SPECIFICATION

P/N	PKG	QTY
AZ9143-04F-MS	DFN2510	3000



Compiance



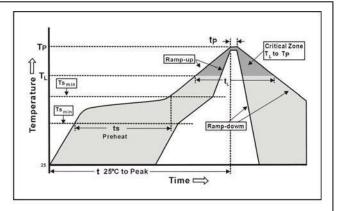
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Transient Voltage Suppressors for ESD Protection

Soldering Parameters

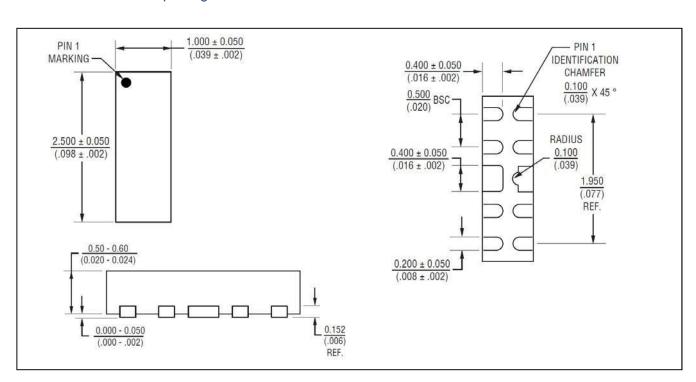
Reflow Co	ondition	Fb – Free assembly	
	-Temperature Min (T _{s(Min)})	150°C	
Pre Heat	- Temperature Max (T _{s(Max)})	200°C	
	-Time (Min to max) (t _s)	60 - 180 secs	
Average r (T _L) to pea	ramp up rate (Liquidus) Temp	3°C/second Max	
T _{s (Max)} to 1	- Ramp-up Rate	3°C/second Max	
Reflow	-Temperature (T _L) (Liquidus)	217°C	
	-Temperature (t _L)	60 – 150 seconds	
Peak Temperature (Tp)		250+0/-5 °C	
Time within 5°C of actual peak Temperature (t _s)		20 – 40 seconds	
Ramp-dowm Rate		6°C/second Max	
Time 25°C to peak Temperature (Tp)		8 minutes Max.	
Do not exceed		260°C	



Package Outline

Plastic surface mounted package

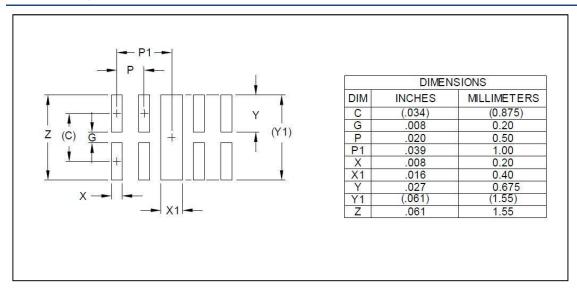
DFN2510





Transient Voltage Suppressors for ESD Protection

Soldering Footprint



Package And Marking Information

Device	Package	Shipping	Reel Size
TAPING	DFN2510	3000/Reel	7 inch

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